NSN 5962-01-341-2449

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View Online at https://aerobasegroup.com/nsn/5962-01-341-2449

Overall Height
Overall Height:
0.500 inches
Body Length:
Between 1.560 inches and 1.640 inches
Body Width:
0.610 inches
Body Height:
0.285 inches
Maximum Power Dissipation Rating:
2.0 watts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
Features Provided:
Hermetically sealed and burn in and w/enable and bidirectional
Inclosure Material:
Ceramic
Inclosure Configuration:
Dual-in-line
Output Logic Form:
Transistor-transistor logic
Input Circuit Pattern:
28 input
Current Rating Per Characteristic:
5.00 milliamperes average forward current averaged over a full 60-hz cycle not applicable
Terminal Surface Treatment:
Solder
Product Name:
Memory module assembly
Voltage Rating And Type Per Characteristic:
-500.0 millivolts power source and 7.0 volts power source
Capitance Rating Per Characteristic:
Err-060 and err-060
Time Rating Per Chacteristic:
300.00 nanoseconds access
Memory Device Type:
Eeprom
Test Data Document:
96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).
Terminal Type And Quantity:

32 printed circuit

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Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

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